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DIODE, POWER, SCHOTTKY RECTIFIER

BASED ON TYPE STPS80A45C AND STPS40A45C

ESCC Detail Specification No. 5106/024

Issue 1

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1 <u>GENERAL</u>

1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 <u>The ESCC Component Number</u>

The ESCC Component Number shall be constituted as follows:

Example: 510602401

- Detail Specification Reference: 5106024
- Component Type Variant Number: 01

1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

| Variant Number | Based on Type | Case | Average Output Rectified Current per Device (Io) (A) | Description | Lead/Terminal Material and Finish | Weight Max (g) |
|-------------------|---------------|----------|---|----------------------------------|---|----------------------|
| 01 | STPS80A45C | SMD.5 | 80 | Dual diode, common cathode | Q14 | 0.92 |
| 02 | STPS40A45C | TO-254AA | 40 | Dual diode, common cathode | S14 | 9.4 |
| 03 | STPS40A45C | TO-254AA | 40 | Dual diode, common cathode | S4 | 9.4 |

The lead/terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.



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1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

| Characteristics | Symbols | Maximum Ratings | Unit | Remarks |
|---|----------------------|------------------------|------|------------|
| Forward Surge Current (per diode) | I _{FSM} | 200 | А | Notes 1, 2 |
| Working Peak Reverse Voltage | Vrwm | 45 | V | |
| Average Output Rectified Current Variant 01 (per diode) Variant 01 (per device) Variants 02 and 03 (per diode) Variants 02 and 03 (per device) | lo | 40 80 40 40 | A | Note 3 |
| Operating Temperature Range (Case Temperature) | T _{op} | -65 to +175 | °C | |
| Junction Temperature | Tj | +175 | °C | Note 4 |
| Storage Temperature Range | T _{stg} | -65 to +175 | °C | |
| Soldering Temperature | T _{sol} | +245 | °C | Note 5 |
| Thermal Resistance, Junction to Case Variant 01 (per diode) Variant 01 (per device) Variants 02 and 03 (per diode) Variants 02 and 03 (per device) | R _{th(j-c)} | 3.4 2.8 2 1.5 | °C/W | |
| Thermal Resistance, Junction to Ambient Variant 01 Variants 02 and 03 | Rth(j-a) | 100 50 | °C/W | Note 4 |

NOTES:

- 1. Sinusoidal pulse of 10ms duration.
- 2. At $T_{amb} \leq 25^{\circ}C$.
- 3. For Variant 01 per diode: At $T_{case} > +63.5^{\circ}$ C, derate linearly to 0A at +175°C. For Variant 01 per device: At $T_{case} > -8.6^{\circ}$ C, derate linearly to 0A at +175°C. For Variants 02 and 03 per diode: At $T_{case} > +109.4^{\circ}$ C, derate linearly to 0A at +175°C. For Variants 02 and 03 per device: At $T_{case} > +134.8^{\circ}$ C, derate linearly to 0A at +175°C.
- 4. To avoid the risk of thermal runaway of a diode, on its own heatsink, the following condition shall be applied: $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$
- 5. Duration 5s maximum and the same package shall not be resoldered until 3 minutes have elapsed.



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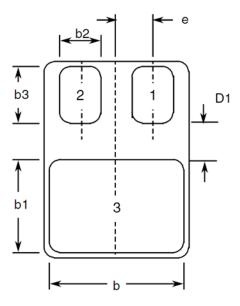
1.6 HANDLING PRECAUTIONS

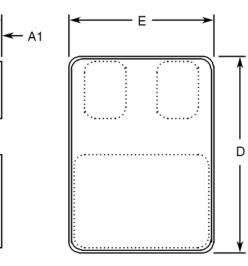
These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are categorised as Class 3 per ESCC Basic Specification No. 23800 with a Minimum Critical Path Failure Voltage of 8kV.

The TO-254AA package contains Beryllium Oxide (BeO) and therefore must not be ground, machined, sandblasted or subjected to any mechanical operation which will produce dust. The case must not be subjected to any chemical process (e.g. etching) which will produce fumes.

- 1.7 <u>PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION</u> Consolidated Notes are given in Para. 1.7.3.
- 1.7.1 Surface Mount Package (SMD.5) 3 Terminal (Variant 01)

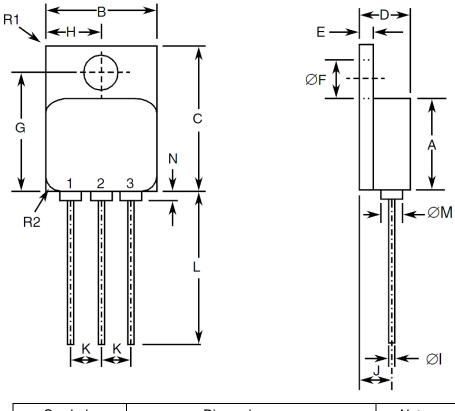




| Symbolo | Dimensi | Notes | |
|---------|---------|-------|-------|
| Symbols | Min | Max | notes |
| A | 2.84 | 3.15 | |
| A1 | 0.25 | 0.51 | |
| b | 7.13 | 7.39 | |
| b1 | 5.58 | 5.84 | |
| b2 | 2.28 | 2.54 | 2 |
| b3 | 2.92 | 3.18 | 2 |
| D | 10.03 | 10.28 | |
| D1 | 0.76 | - | 2 |
| E | 7.39 | 7.64 | |
| е | 1.91 | 2 | |



1.7.2 Metal Flange Mount Package (TO-254AA) - 3 Lead (Variants 02 and 03)



| Symbols | Dimensi | Dimensions mm | | |
|---------|--------------|---------------|---|--|
| | Min | Max | | |
| А | 13.59 | 13.84 | | |
| В | 13.59 | 13.84 | | |
| С | 20.07 | 20.32 | | |
| D | 6.3 | 6.7 | | |
| E | 1 | 1.35 | | |
| ØF | 3.5 | 3.9 | | |
| G | 16.89 | 17.4 | | |
| н | 6.86 | BSC | | |
| ØI | 0.89 | 1.14 | 3 | |
| J | 3.81 | BSC | | |
| К | 3.81 | BSC | | |
| L | 12.95 | 14.5 | | |
| ØM | 3.05 Typical | | 3 | |
| Ν | - | 0.71 | 3 | |
| R1 | - | 1 | 4 | |
| R2 | 1.65 T | ypical | 5 | |



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- 1.7.3 Notes to Para. 1.7 Physical Dimensions and Terminal Identification
 - 1. Terminal identification is specified by the component's geometry. See Para. 1.8 Functional Diagram for the terminal connections.
 - 2. 2 places.
 - 3. 3 places.
 - 4. Radius of heatsink flange corner, 4 places.
 - 5. Radius of body corner, 4 places.

1.8 FUNCTIONAL DIAGRAM

 Terminal 1: Anode 1

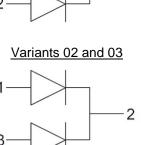
 Terminal 2: Anode 2

 Terminal 3: Common cathode

 2

 Variants 02 and

Terminal 1: Anode 1 Terminal 2: Common Cathode Terminal 3: Anode 2



3

NOTES:

- 1. For Variant 01, the lid is not connected to any terminal.
- 2. For Variants 02 and 03, the case is not connected to any lead.

1.9 MATERIALS AND FINISHES

Materials and finishes shall be as follows:

(a) Case

For the surface mount package the case shall be hermetically sealed and have a ceramic body with a Kovar lid.

For the metal flange mount package the case shall be hermetically sealed and have a metal body. The leads pass through ceramic eyelets brazed into the frame and the lid shall be welded.

(b) Lead/Terminal Finish As specified in Para. 1.4.2 Component Type Variants.



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2 <u>REQUIREMENTS</u>

2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 <u>Deviations from the Generic Specification</u> None.

2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number (see Para. 1.4.1).
- (c) Traceability information.
- (d) Warning sign for beryllium oxide (only applicable to Variants 02 and 03).

2.3 <u>TERMINAL STRENGTH</u>

For Variants 02 and 03, the test conditions for Terminal Strength, tested as specified in the ESCC Generic Specification, shall be as follows:

• Test Condition: A, tension, with an applied force of 10N for a duration of 10s.

2.4 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures. Consolidated notes are given in Para. 2.4.3.

2.4.1 <u>Room Temperature Electrical Measurements</u> The measurements shall be performed at $T_{amb} = +25 \pm 3^{\circ}C$.

| Characteristics | Symbols | MIL-STD-750 | | | Limits | |
|-----------------|-----------------|-------------|-----------------------------------|-----|--------|----|
| | | Test Method | Note 1 | Min | Max | |
| Reverse Current | I _R | 4016 | DC Method V _R = 45V | - | 25 | μA |
| Forward Voltage | V _{F1} | 4011 | I⊧ = 5A, Note 2 | - | 0.51 | V |
| | VF2 | 4011 | I⊧ = 10A, Note 2 | - | 0.57 | V |
| | V _{F3} | 4011 | I⊧ = 20A, Note 2 | - | 0.67 | V |
| | V _{F4} | 4011 | I _F = 30A, Note 2 | - | 0.75 | V |
| | V_{F5} | 4011 | I _F = 40A, Note 2 | - | 0.82 | V |



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| Characteristics | Symbols | MIL-STD-750 Test Conditions Limits | | nits | Units | |
|---|----------------------|------------------------------------|---|---------------------|--------|------|
| | | Test Method | Note 1 | Min | Max | |
| Capacitance | С | 4001 | V _R = 10V V _{sig} = 30mV (p-p) max f = 1MHz | - | 610 | pF |
| Critical Rate of Rise of Reverse Voltage | dV/dt | - | - | - | 10000 | V/µs |
| Thermal Impedance, Junction to Case | Z _{th(j-c)} | 3101 | Note 3 | ΔV _F , I | Note 4 | °C/W |

2.4.2 <u>High and Low Temperatures Electrical Measurements</u>

| Characteristics | Symbols | MIL-STD-750 | Test Conditions | Limits | | Units |
|-----------------|-----------------|--|---|--------|------|-------|
| | | Test Method | Notes 1, 5 | Min | Max | |
| Reverse Current | IR | 4016 | T _{amb} = +125 (+0 -5) °C DC Method V _R = 45V | - | 18 | mA |
| Forward Voltage | V _{F1} | 4011 | T _{amb} = +125 (+0 -5) °C I _F = 5A, Note 2 | - | 0.4 | V |
| | - | | T _{amb} = -55 (+5 -0) °C I⊧ = 5A, Note 2 | - | 0.59 | V |
| | | T _{amb} = +125 (+0 -5) °C I _F = 10A, Note 2 | - | 0.49 | V | |
| | | T _{amb} = -55 (+5 -0) °C I _F = 10A, Note 2 | - | 0.63 | V | |
| | | T _{amb} = +125 (+0 -5) °C I _F = 20A, Note 2 | - | 0.61 | V | |
| | | | T _{amb} = -55 (+5 -0) °C I _F = 20A, Note 2 | - | 0.7 | V |
| | V _{F4} | 4011 | T _{amb} = +125 (+0 -5) °C I _F = 30A, Note 2 | - | 0.68 | V |
| | | | T _{amb} = -55 (+5 -0) °C I⊧ = 30A, Note 2 | - | 0.76 | V |
| | V _{F5} | 4011 | T _{amb} = +125 (+0 -5) °C I _F = 40A, Note 2 | - | 0.74 | V |
| | | | T _{amb} = -55 (+5 -0) °C I _F = 40A, Note 2 | - | 0.82 | V |

2.4.3 <u>Notes to Electrical Measurements Tables</u>

- 1. Measurement per each diode.
- 2. Pulsed measurement: Pulse Width \leq 680µs, Duty Cycle \leq 2%.
- 3. Performed only during Screening Tests Parameter Drift Values (Initial Measurements), go-nogo.
- 4. The limits for ΔV_F shall be defined by the Manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the R_{th(j-c)} limits specified in Para. 1.5 Maximum Ratings.
- 5. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.



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2.5 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at T_{amb} = +25 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.4.1, Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

| Characteristics | Symbols | | Units | | |
|-----------------|-----------------|-----------------------|----------|------|----|
| | | Drift | Absolute | | |
| | | Value Δ | Min | Max | |
| Reverse Current | I _R | ±5 or (1) ±100% | - | 25 | μA |
| Forward Voltage | V _{F1} | ±0.05 | - | 0.51 | V |
| | V _{F2} | ±0.05 | - | 0.57 | V |
| | V _{F3} | ±0.05 | - | 0.67 | V |
| | VF4 | ±0.05 | - | 0.75 | V |
| | V _{F5} | ±0.05 | - | 0.82 | V |

NOTES:

1. Whichever is the greater referred to the initial value.

2.6 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at $T_{amb} = +25 \pm 3^{\circ}C$.

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.4.1, Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

| Characteristics | Symbols | Limits | | Units |
|-----------------|-----------------|--------|------|-------|
| | | Min | Max | |
| Reverse Current | I _R | - | 25 | μA |
| Forward Voltage | V _{F1} | - | 0.51 | V |
| | V _{F2} | - | 0.57 | V |
| | V _{F3} | - | 0.67 | V |
| | V_{F4} | - | 0.75 | V |
| | V_{F5} | - | 0.82 | V |



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2.7 <u>HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS</u>

| Characteristics | Symbols | Test Conditions | Units |
|---------------------|----------------|-----------------|-------|
| Ambient Temperature | T_{amb} | +80 (+0 -5) | °C |
| Reverse Voltage | V _R | 36 | V |
| Duration | t | ≥ 48 | Hours |

2.8 POWER BURN-IN CONDITIONS

| Characteristics | Symbols | Test Conditions | Units |
|----------------------------------|------------------|-----------------|-------|
| Ambient Temperature | T _{amb} | +25 (+0 -5) | °C |
| Junction Temperature | TJ | +175 (+0 -5) | °C |
| Average Output Rectified Current | lo | Note 1 | А |
| Duration | t | ≥ 168 | Hours |

NOTES:

1. The output current may be adjusted, within the given limit range, to attain the specified junction temperature.

2.9 OPERATING LIFE CONDITIONS

The conditions shall be as specified in Para. 2.8, Power Burn-in Conditions.

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APPENDIX 'A'

AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

| ITEMS AFFECTED | DESCRIPTION OF DEVIATIONS |
|--|---|
| Para. 2.1.1, Deviations from the Generic Specification: Deviations from Production Control – Chart F2 | Special In-Process Controls - Internal Visual Inspection: Wedge bonds equal to 1.1 wire diameter are acceptable for bonding with a V-Groove tool. |
| Para. 2.1.1, Deviations from the Generic Specification: Deviations from Screening Tests for Packaged Components – Chart F3A | Solderability: Solderability is not applicable unless specifically stipulated in the Purchase Order. |
| | Room Temperature Electrical Measurements: Capacitance and Critical Rate of Rise of Reverse Voltage may be considered guaranteed but not tested if successful pilot lot testing has been performed in accordance with STMicroelectronics "Acceptation wafers" internal procedure as specified in the PID, which includes AC characteristic measurements per the Detail Specification. A summary of the pilot lot testing shall be provided if required by the Purchase Order. |

APPENDIX 'B'

ADDITIONAL DATA - STMICROELECTRONICS (F)

(a) Derating for Space Application

The derating for space applications was originally obtained on STPS40A45 devices under the following test conditions. A Post-Irradiation Gate Stress (PIGS) test has been done after irradiation. The testing was performed in a vacuum at UCL (Louvain-la-Neuve, Belgium):

lons used: Xe LET = 62.5MeV/(mg/cm²) Energy = 995MeV Range = 73.1µm(Si)

These components are susceptible to Single Event Burn-out (SEB) if operated in a space environment unless the following derating is applied:

| V _R (V) | 45 | 33.75 |
|-------------------------------|-----|-------|
| LET (MeV.cm ² /mg) | | |
| 62.5 | SEB | ОК |